

16 Ω , Low Charge Injection and Leakage, +12 V / +5 V / +3 V / $\pm$ 5 V Quad SPST Switches

DESCRIPTION

The DG441LE, DG442LE monolithic quad single-pole-single-throw analog switches are designed to provide high speed, low error switching of analog signals. The DG441LE has a normally closed function. The DG442LE has a normally open function.

The DG441LE, DG442LE feature low charge injection of a few picocoulombs over the full analog switch range. Combining low on resistance (16 Ω , typ.), low parasitic capacitance ($C_{D(ON)}$ 15 pF), and fast switching speed (t_{ON} , 18 ns, typ.), the devices are ideal for data acquisition, sample-and-hold, and ADC input circuit designs.

The DG441LE, DG442LE operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with $\pm$ 3 V to $\pm$ 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The DG441LE, DG442LE are available in 16 lead TSSOP, and SOIC packages.

FEATURES

- 3 V to 16 V single supply or $\pm$ 3 V to $\pm$ 8 V dual supply
- On-resistance $R_{DS(on)}$: 16 Ω
- Fast switching t_{ON} : 18 ns, typ.
- Low parasitic capacitance:
 $C_{D(ON)}$: 15 pF
 $C_{S(OFF)}$: 5 pF
- Less than 8 pC charge injection over the full signal swing range
- Low leakage: < 10 pA, typ.
- TTL, CMOS compatible
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

BENEFITS

- Wide operation voltage range
- Low signal errors and distortion
- Fast switching time
- Minimized switching glitch

APPLICATIONS

- Automatic test equipment
- Process control and automation
- Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems

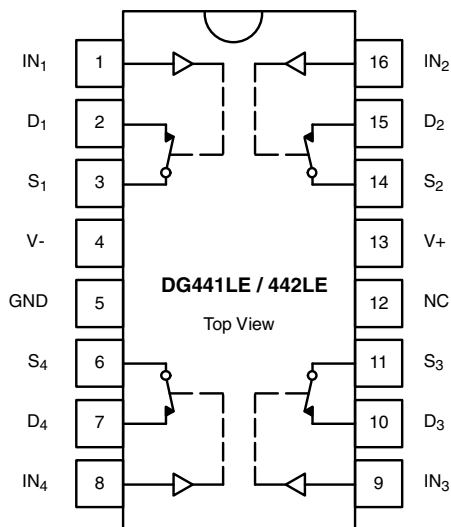


RoHS*
Available

HALOGEN
FREE
Available

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

Dual-In-Line, TSSOP and SOIC



TRUTH TABLE

LOGIC	DG441LE	DG442LE
0	On	Off
1	Off	On

Logic "0" $\leq$ 0.8 V

Logic "1" $\geq$ 2.4 V

**ORDERING INFORMATION**

TEMP. RANGE	CONFIGURATION	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY
-40 °C to +85 °C lead (Pb)-free	DG441LE	16-pin TSSOP	DG441LEDQ-GE3	Tube 360 units
			DG441LEDQ-T1-GE3	Tape and reel, 3000 units
		16-pin SOIC	DG441LEDY-GE3	Tube 500 units
			DG441LEDY-T1-GE3	Tape and reel, 2500 units
	DG442LE	16-pin TSSOP	DG442LEDQ-GE3	Tube 360 units
			DG442LEDQ-T1-GE3	Tape and reel, 3000 units
		16-pin SOIC	DG442LEDY-GE3	Tube 500 units
			DG442LEDY-T1-GE3	Tape and reel, 2500 units

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ °C}$, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
V+ to V-		-0.3 to +18	V
GND to V _A		18	
Digital inputs ^a V _S , V _D		GND -0.3 to (V ₊) + 0.3 or 30 mA, whichever occurs first	
Continuous current (any terminal)		30	mA
Current, S or D (pulsed 1 ms, 10 % duty cycle)		100	
Storage temperature	(DQ, DY suffix)	-65 to +125	°C
	(AK suffix)	-65 to +150	
Power dissipation (packages) ^b	16-pin TSSOP ^c	450	mW
	16-pin narrow body SOIC ^d	650	
ESD human body model (HBM); per ANSI / ESDA / JEDEC® JS-001		2500	V
Latch up current, per JESD78D		400	mA

Notes

- Signals on S_X, D_X, or IN_X exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- All leads welded or soldered to PC board
- Derate 7 mW/°C above 75 °C
- Derate 7.6 mW/°C above 75 °C
- Derate 12 mW/°C above 75 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SPECIFICATIONS ^a (single supply 12 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 12 V, V ₋ = 0 V V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	0	12	0	12	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 10.8 V, V ₋ = 0 V I _S = 10 mA, V _D = 2 V / 9 V	Room	16	-	26	-	26	Ω
			Full	-	-	40	-	35	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 9 V	Room	0.1	-	0.5	-	0.5	
Switch Off Leakage Current	I _{S(off)}	V _D = 1 V / 11 V, V _S = 11 V / 1 V	Room	-	-1	1	-1	1	nA
	I _{D(off)}		Full	-	-15	15	-10	10	
			Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current	I _{D(on)}	V _S = V _D = 11 V / 1 V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{IN} under test = 0.8 V	Full	0.01	-1.5	1.5	-1	1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V	Full	-	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 5 V, see figure 2	Room	18	-	60	-	60	ns
Turn-Off Time	t _{OFF}		Full	-	-	80	-	70	
			Room	18	-	35	-	35	
			Full	-	-	50	-	45	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	6.6	-	-	-	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	68.4	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	114	-	-	-	-	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	5	-	-	-	-	pF
Drain Off Capacitance ^e	C _{D(off)}		Room	6	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}		Room	15	-	-	-	-	
Power Supplies									
Positive Supply Current	I ₊	V _{IN} = 0 V or 12 V	Full	0.03	-	1.5	-	1	μA
Negative Supply Current	I ₋		Room	-	-1	-	-1	-	
			Full	0.002	-7.5	-	-5	-	
Ground Current	I _{GND}		Full	0.002	-1.5	-	-1	-	



SPECIFICATIONS ^a (dual supply ± 5 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = -5 V V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	-5	5	-5	5	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 5 V, V ₋ = -5 V I _S = 10 mA, V _D = ± 3.5 V	Room	18	-	30	-	30	Ω
			Full	-	-	42	-	37	
On-Resistance Match Between Channels ^e	$\Delta R_{DS(on)}$	I _S = 10 mA, V _D = ± 3.5 V	Room	0.1	-	0.5	-	0.5	
Switch Off Leakage Current ^g	I _{S(off)}	V ₊ = 5.5, V ₋ = -5.5 V V _D = ± 4.5 V, V _S = ± 4.5 V	Room	-	-1	1	-1	1	nA
			Full	-	-15	15	-10	10	
	I _{D(off)}		Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current ^g	I _{D(on)}	V ₊ = 5.5 V, V ₋ = -5.5 V V _S = V _D = ± 4.5 V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} under test = 0.8 V	Full	0.05	-1.5	1.5	-1	1	μ A
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} under test = 2.4 V	Full	0.05	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω , C _L = 35 pF V _S = ± 3.5 V, see figure 2	Room	42	-	65	-	65	ns
			Full	-	-	90	-	75	
Turn-Off Time	t _{OFF}		Room	34	-	45	-	45	
			Full	-	-	65	-	55	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω , C _L = 10 nF	Room	5.8	-	-	-	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω , C _L = 5 pF, f = 1 MHz	Room	68.4	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	113	-	-	-	-	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	5	-	-	-	-	pF
Drain Off Capacitance ^e	C _{D(off)}		Room	6	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}		Room	14	-	-	-	-	
Power Supplies									
Positive Supply Current ^e	I ₊	V _{IN} = 0 V or 5 V	Full	0.002	-	1.5	-	1	μ A
Negative Supply Current ^e	I ₋		Room	-0.002	-1	-	-1	-	
			Full	-	-7.5	-	-5	-	
Ground Current ^e	I _{GND}		Full	-0.002	-1.5	-	-1	-	



SPECIFICATIONS ^a (single supply $\pm$ 5 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 5 V, V ₋ = 0 V V _{IN} = 2.4 V, 0.8 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	-	5	-	5	V
Drain-Source On-Resistance ^e	R _{DS(on)}	V ₊ = 4.5 V I _S = 5 mA, V _D = 1 V, 3.5 V	Room	36	-	50	-	50	Ω
			Full	-	-	88	-	75	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 3.5 V	Room	0.5	-	1	-	1	
Dynamic Characteristics									
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 3.5 V, see figure 2	Room	53	-	70	-	70	ns
			Hot	-	-	90	-	80	
Turn-Off Time ^e	t _{OFF}		Room	34	-	50	-	50	
			Hot	-	-	70	-	60	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	3.3	-	-	-	-	pC
Power Supplies									
Positive Supply Current ^e	I ₊	V _{IN} = 0 V or 5 V	Full	10	-	200	-	100	μA
Negative Supply Current ^e	I ₋		Room	-0.002	-1	-	-1	-	
			Full	-	-7.5	-	-5	-	
Ground Current ^e	I _{GND}		Full	-10	-200	-	-100	-	



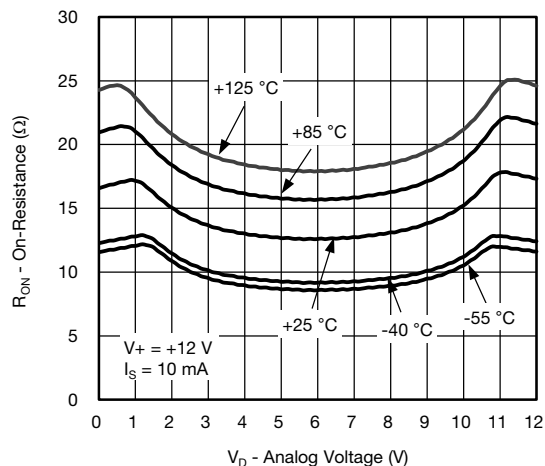
SPECIFICATIONS ^a (single supply 3 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 3 V, V ₋ = 0 V V _{IN} = 0.4 V ^f	TEMP. ^b	TYP. ^c	A SUFFIX LIMITS -55 °C to +125 °C		D SUFFIX LIMITS -40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full	-	0	3	0	3	V
Drain-Source On-Resistance	R _{DS(on)}	V ₊ = 3.0 V, V ₋ = 0 V I _S = 5 mA, V _D = 0.5 V, 2.2 V	Room	71	52	90	52	90	Ω
			Full	-	-	110	-	102	
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 5 mA, V _D = 2.2 V	Room	1	-	3	-	3	
Switch Off Leakage Current ^g	I _{S(off)}	V ₊ = 3.3, V ₋ = 0 V V _D = 1 V, 2 V, V _S = 2 V, 1 V	Room	-	-1	1	-1	1	nA
			Full	-	-15	15	-10	10	
	I _{D(off)}		Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Channel On Leakage Current ^g	I _{D(on)}	V ₊ = 3.3 V, V ₋ = 0 V V _S = V _D = 1 V, 2 V	Room	-	-1	1	-1	1	
			Full	-	-15	15	-10	10	
Digital Control									
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} under test = 0.4 V	Full	0.005	-1.5	1.5	-1	1	μA
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} under test = 2.4 V	Full	0.005	-1.5	1.5	-1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 1.5 V, see figure 2	Room	141	-	200	-	200	ns
			Full	-	-	220	-	210	
Turn-Off Time	t _{OFF}		Room	84	-	120	-	120	
			Full	-	-	140	-	130	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	2	-	-	-	-	pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	68	-	-	-	-	dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	107	-	-	-	-	
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	6	-	-	-	-	pF
Drain Off Capacitance ^e	C _{D(off)}		Room	7	-	-	-	-	
Channel On Capacitance ^e	C _{D(on)}		Room	15	-	-	-	-	

Notes

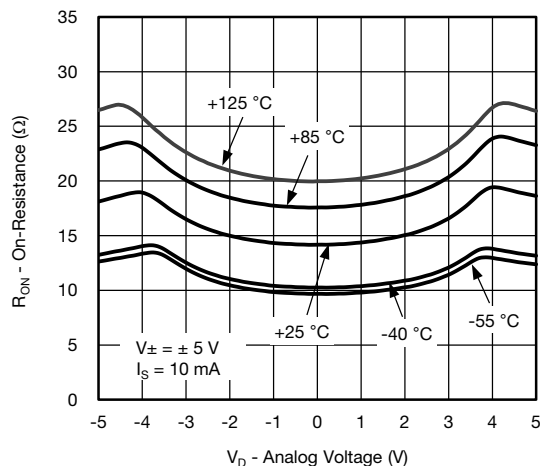
- a. Refer to PROCESS OPTION FLOWCHART
- b. Room = 25 °C, full = as determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = input voltage to perform proper function
- g. Leakage parameters are guaranteed by worst case test conditions and not subject to test



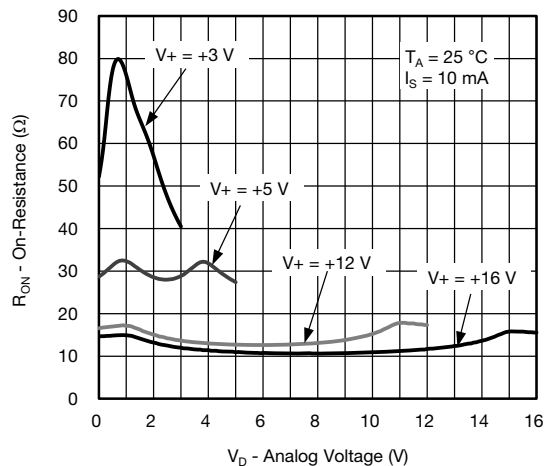
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



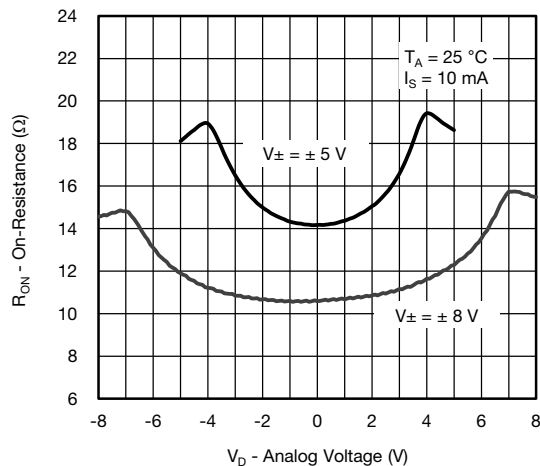
R_{DS(on)} vs. Analog Voltage and Temperature



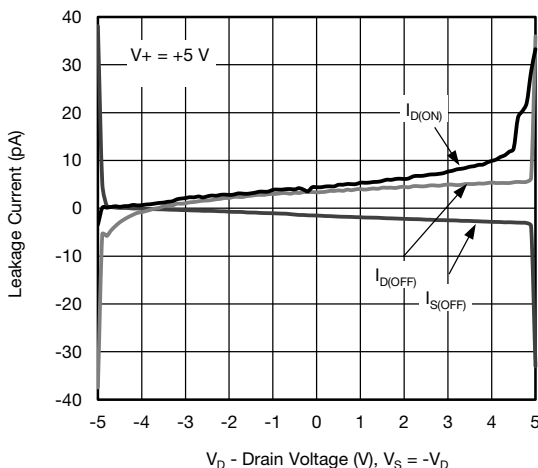
R_{DS(on)} vs. Drain Voltage and Temperature



R_{DS(on)} vs. Analog Voltage



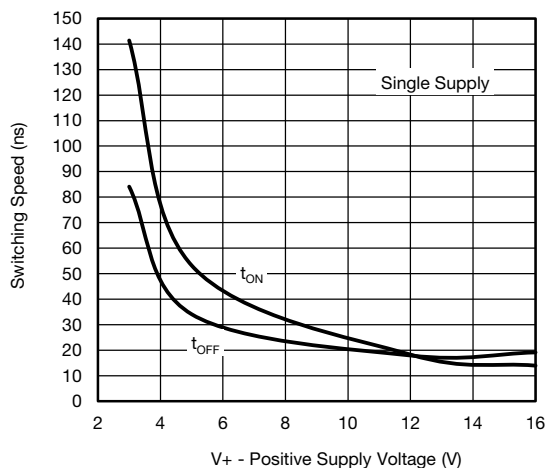
R_{DS(on)} vs. Analog Voltage



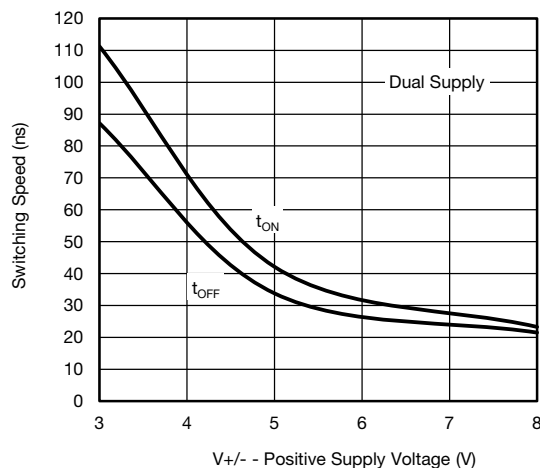
**Leakage Current vs. Drain Voltage
(Dual Supply)**



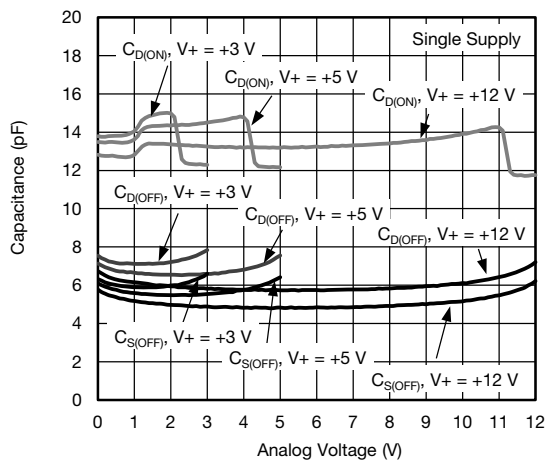
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



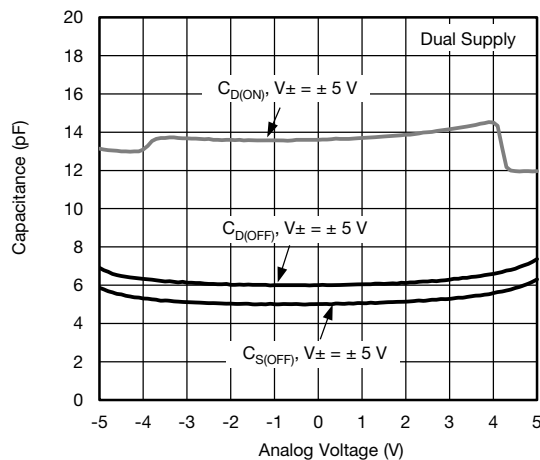
Switching Time vs. Single Supply



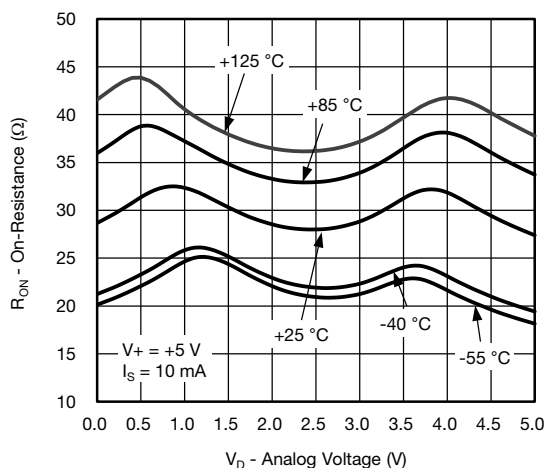
Switching Time vs. Dual Supply



**Capacitance vs. Analog Voltage
(Single Supply)**



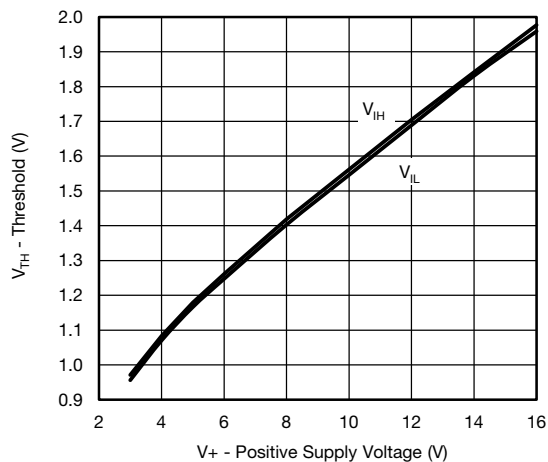
**Capacitance vs. Analog Voltage
(Dual Supply)**



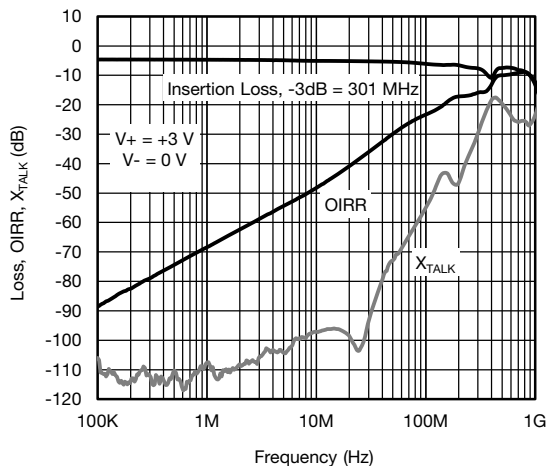
$R_{DS(on)}$ vs. Analog Voltage and Temperature



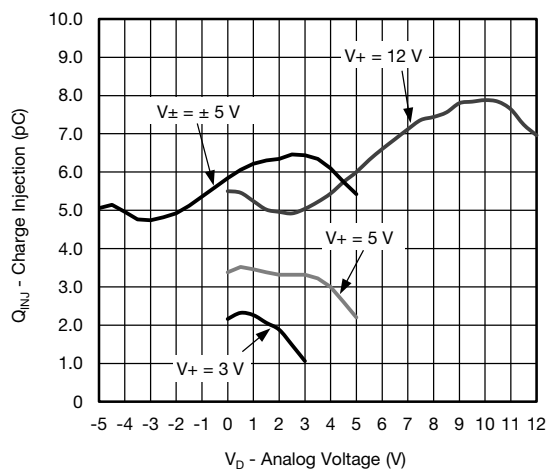
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



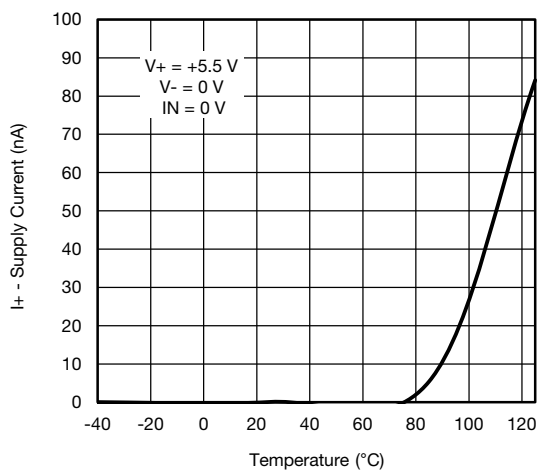
Input Threshold vs. Single Supply Voltage



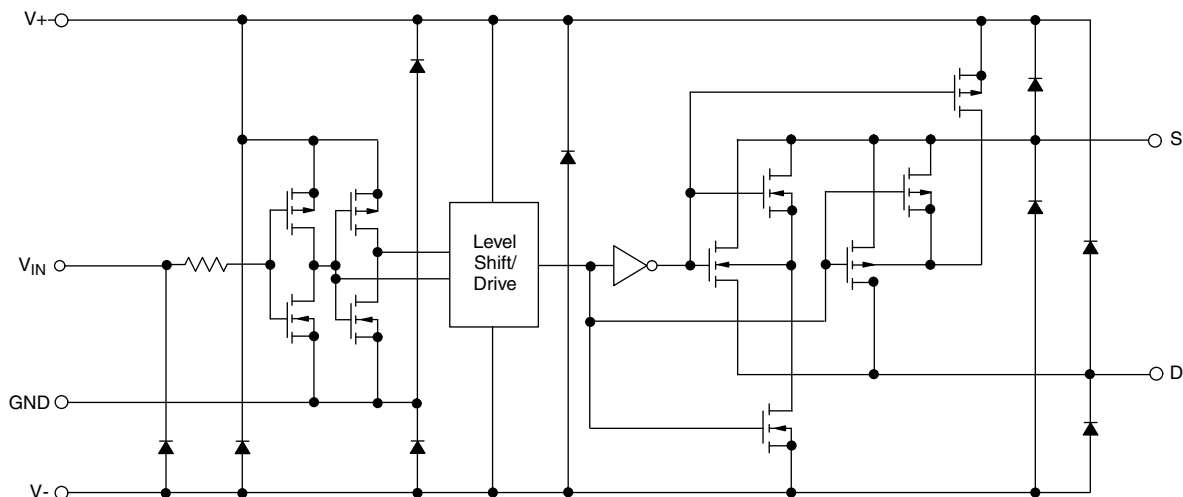
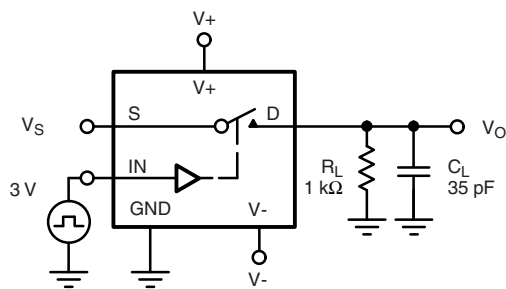
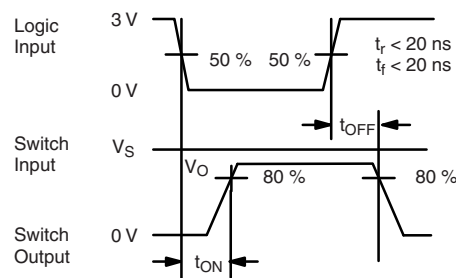
Insertion Loss, Off Isolation and Crosstalk vs. Frequency (Single Supply)



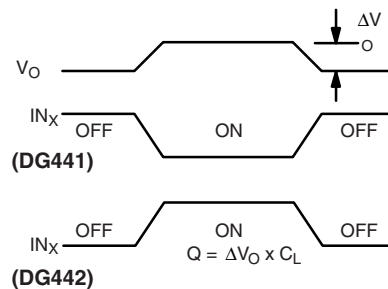
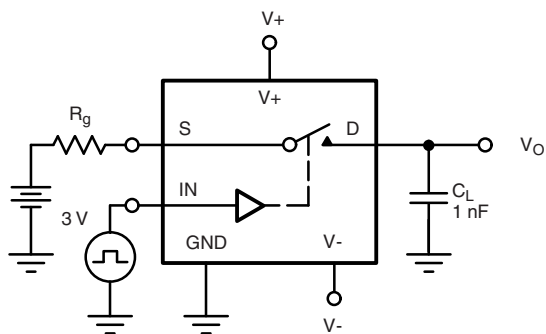
Charge Injection vs. Analog Voltage

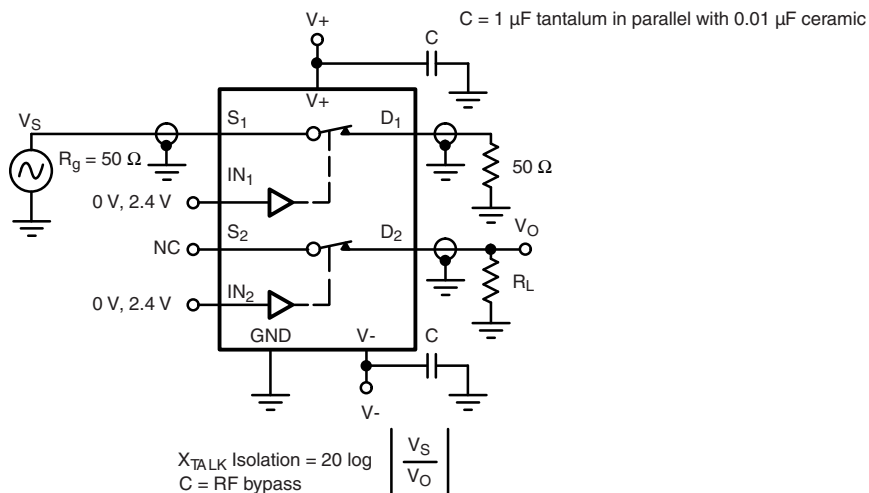
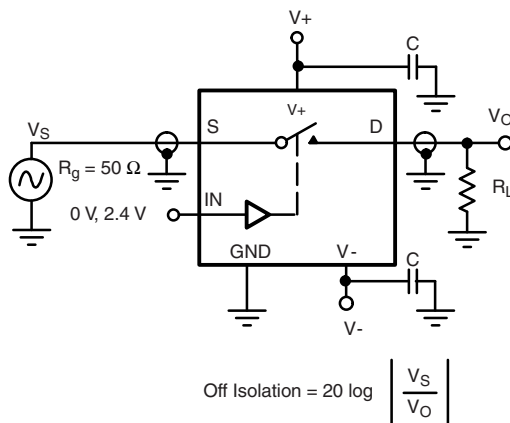
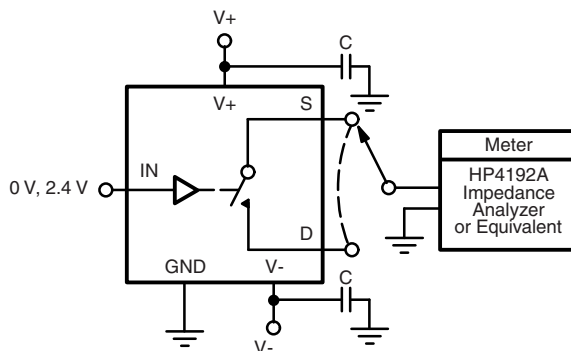


Supply Current vs. Temperature

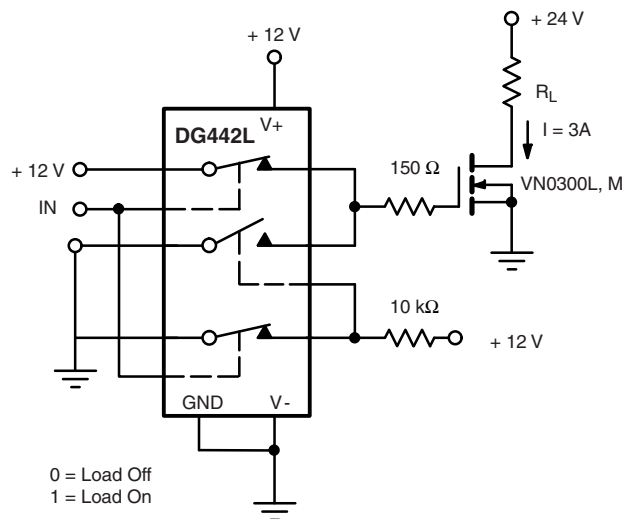
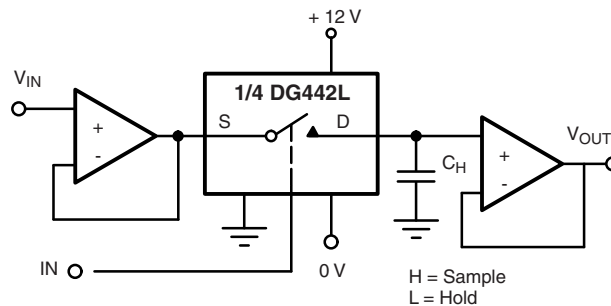
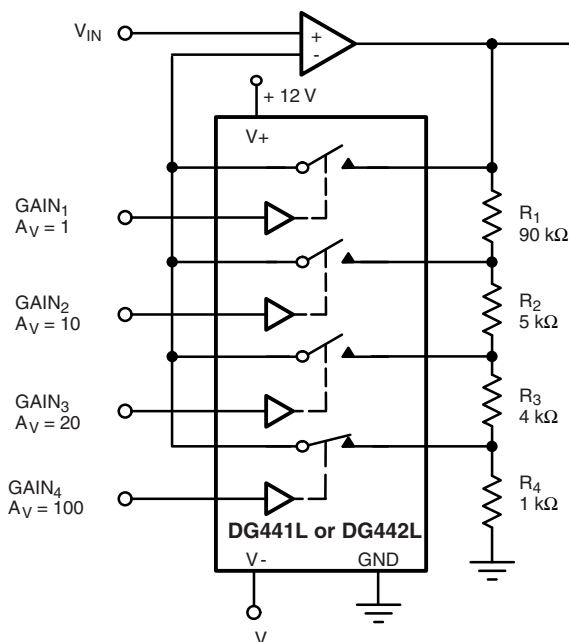
SCHEMATIC DIAGRAM (typical channel)

Fig. 1
TEST CIRCUITS

 C_L (includes fixture and stray capacitance)


Note: Logic input waveform is inverted for DG442.

Fig. 2 - Switching Time

Fig. 3 - Charge Injection

TEST CIRCUITS

Fig. 4 - Crosstalk

Fig. 5 - Off Isolation

Fig. 6 - Source / Drain Capacitances

APPLICATIONS


Fig. 7 - Power MOSFET Driver

Fig. 8 - Open Loop Sample-and-Hold


Gain error is determined only by the resistor tolerance. Op amp offset and CMRR will limit accuracy of circuit.

With SW₄ Closed

$$\frac{V_{OUT}}{V_{IN}} = \frac{R_1 + R_2 + R_3 + R_4}{R_4} = 100$$

Fig. 9 - Precision-Weighted Resistor Programmable-Gain Amplifier



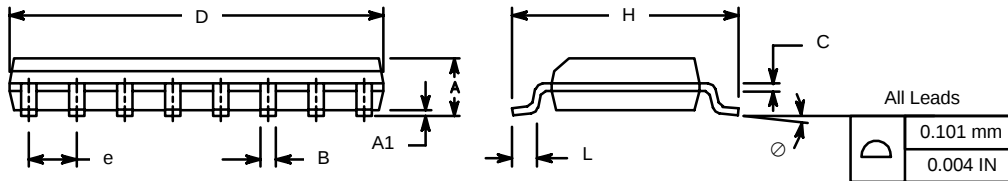
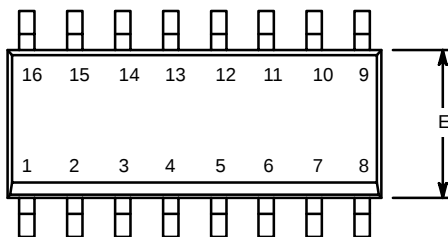
PRODUCT SUMMARY				
Part number	DG441LE	DG441LE	DG442LE	DG442LE
Status code	2	2	2	2
Configuration	SPST x 4, NC	SPST x 4, NC	SPST x 4, NO	SPST x 4, NO
Single supply min. (V)	3	3	3	3
Single supply max. (V)	16	16	16	16
Dual supply min. (V)	3	3	3	3
Dual supply max. (V)	8	8	8	8
On-resistance (Ω)	16	16	16	16
Charge injection (pC)	6.6	6.6	6.6	6.6
Source on capacitance (pF)	15	15	15	15
Source off capacitance (pF)	5	5	5	5
Leakage switch on typ. (nA)	-	-	-	-
Leakage switch off max. (nA)	1	1	1	1
-3 dB bandwidth (MHz)	-	-	-	-
Package	SO-16 (narrow) AS	TSSOP-16	SO-16 (narrow) AS	TSSOP-16
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare, portable	Multi purpose, instrumentation, medical and healthcare, portable	Multi purpose, instrumentation, medical and healthcare, portable	Multi purpose, instrumentation, medical and healthcare, portable
Interface	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes
Turn on time max. (ns)	60	60	60	60
Crosstalk and off isolation	-113	-113	-113	-113

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76754.



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

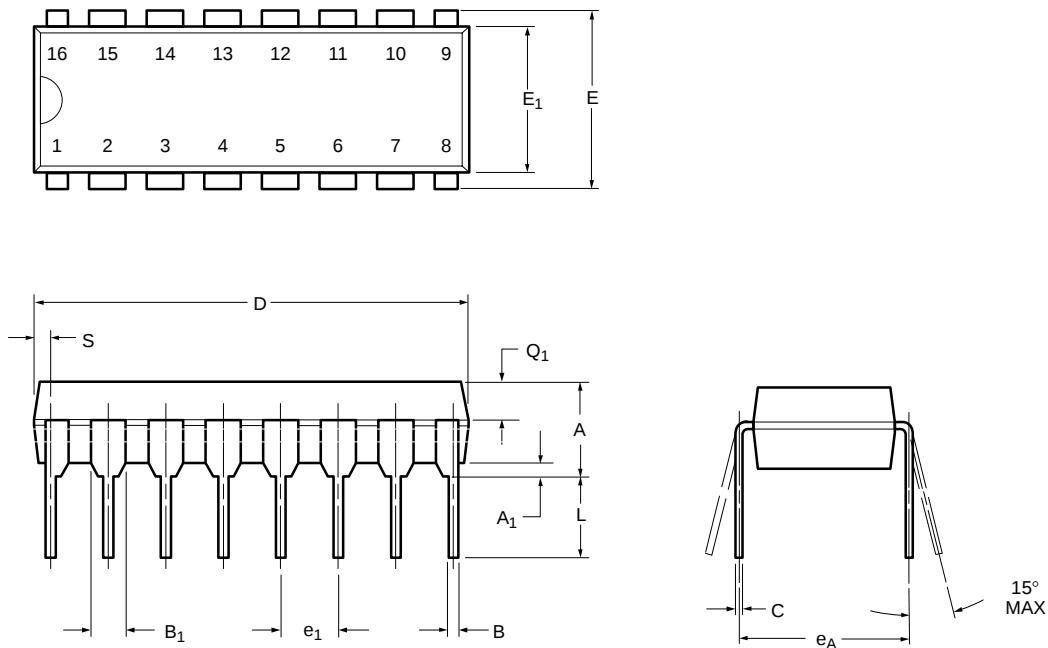


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



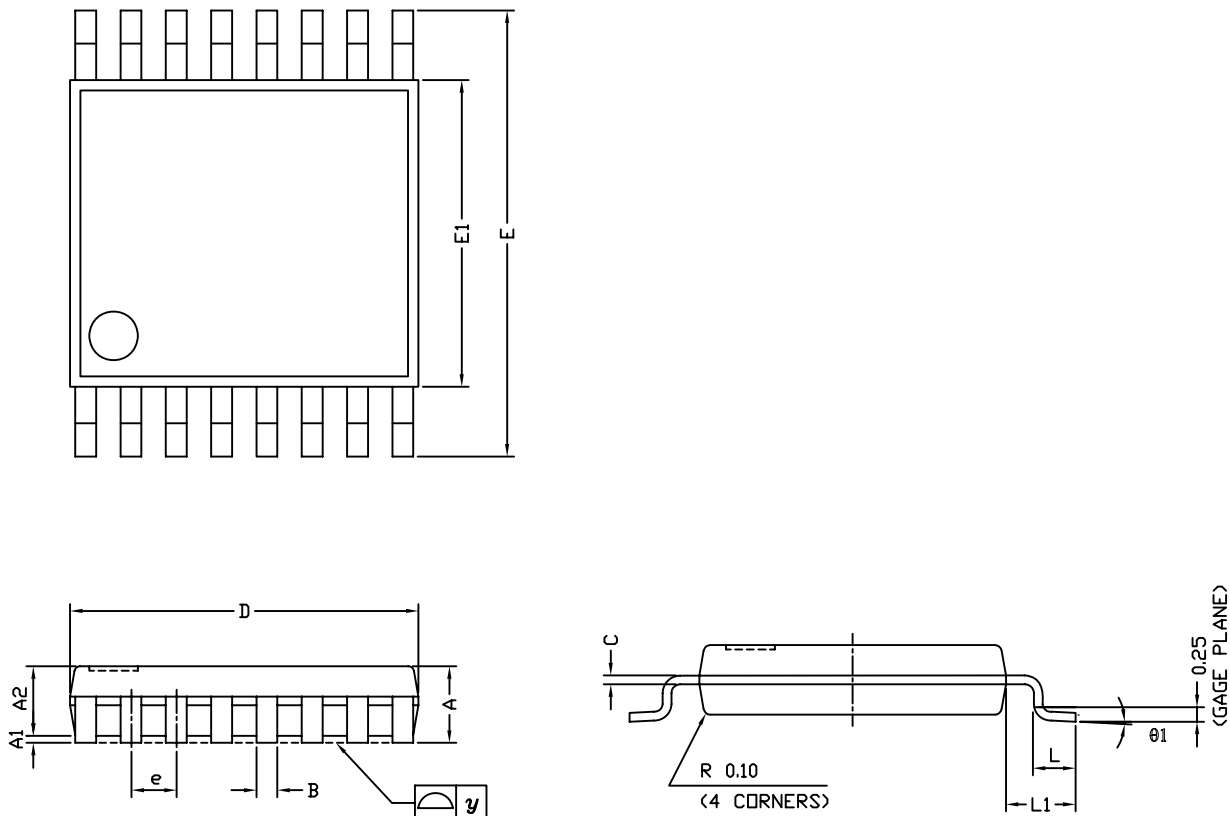
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A ₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B ₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E ₁	5.59	7.11	0.220	0.280
e ₁	2.29	2.79	0.090	0.110
e _A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q ₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

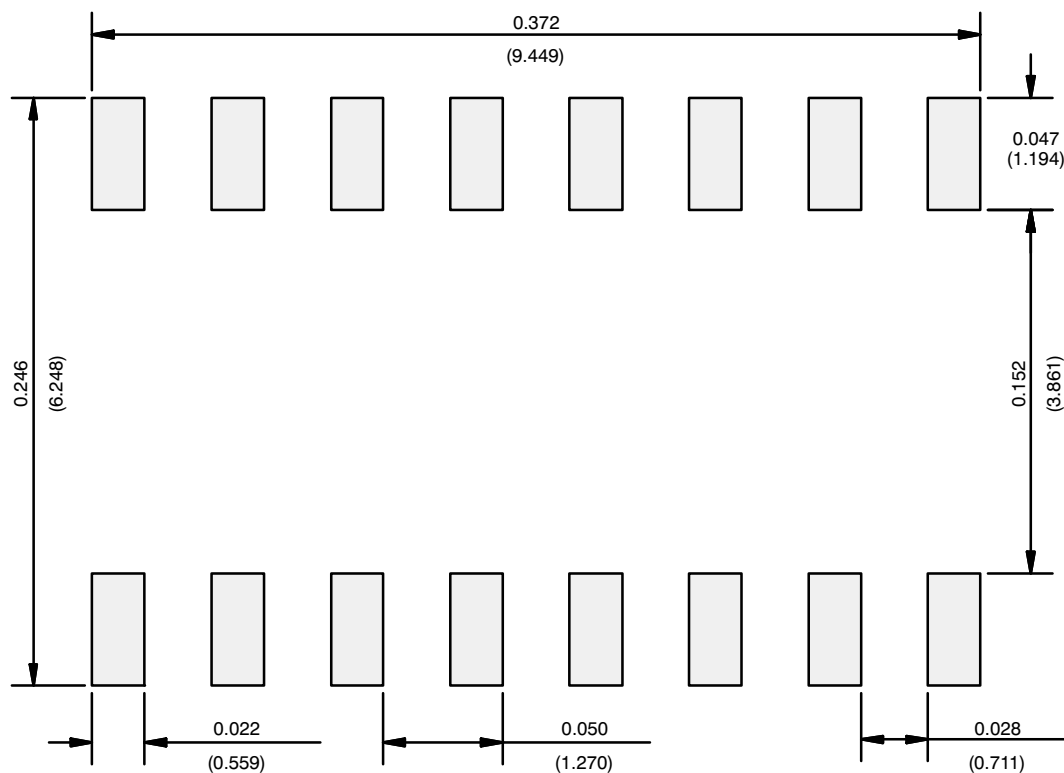


RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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